

#### Features

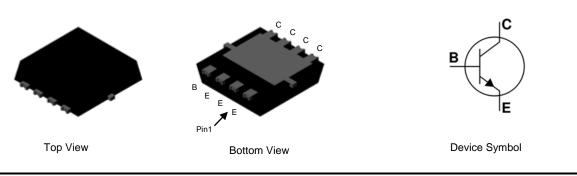
- BVCEO > 60V
- Small Form Factor Thermally Efficient Package. Enables Higher Density End Products
- Ic = 6A Continuous Collector Current
- ICM = 20A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 60mV @ 1A</li>
- h<sub>FE</sub> Specified up to 10A for a High Gain Hold up
- Complementary PNP Type: DXTP03060BFG
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

# Mechanical Data

- Case: PowerDl<sup>®</sup>3333-8
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.03 grams (Approximate)

#### Applications

- MOSFET & IGBT Gate Drivers
- Solenoid, Relay And Actuator Drivers
- DC to DC Converters
- Motor Control



#### Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DXTN03060BFG-7	Standard	2J3	7	12	2,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

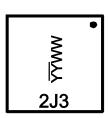
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**

Notes:

PowerDI3333-8 (SWP) (Type UX)

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2J3= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 21 = 2021) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	100	V
Collector-Emitter Voltage	Vceo	60	V
Emitter-Base Voltage	Vebo	7	V
Continuous Collector Current	lc	6	А
Peak Pulse Current	Ісм	20	A

#### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	1.2	W
Power Dissipation	(Note 6)	- PD	2.7	W
Thermal Desistance, Junction to Ambient	(Note 5)	Devi	107	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	48	°C/W
Thermal Resistance, Junction to Leads (Note 7)		Rejl	8.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

# ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Charge Device Model	CDM	1,000	V	C5

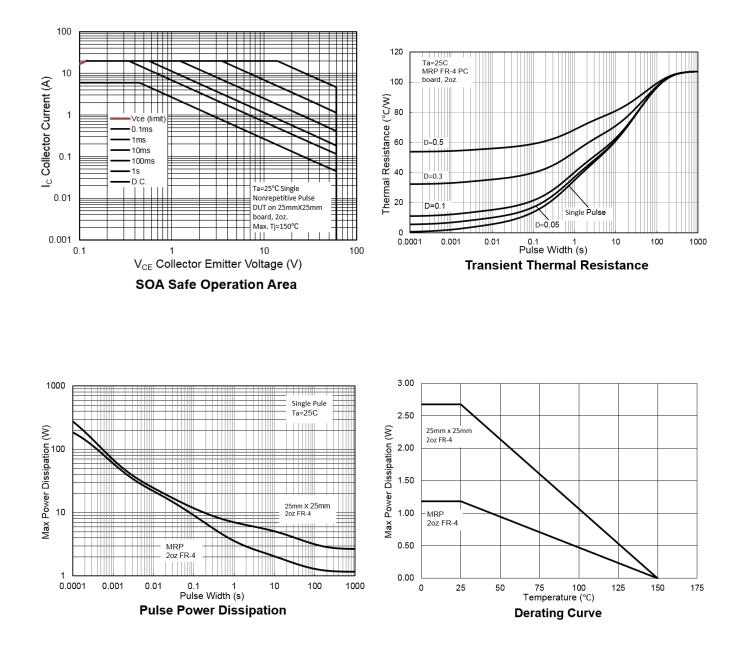
Notes:

5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state. 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.

Thermal resistance from junction to solder-point (at the collector tab).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





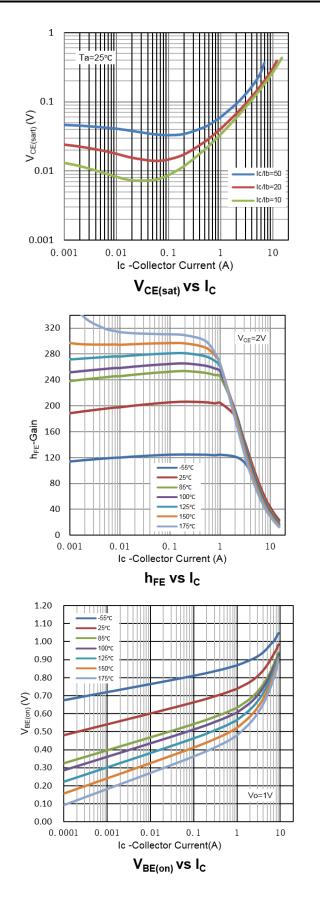
# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

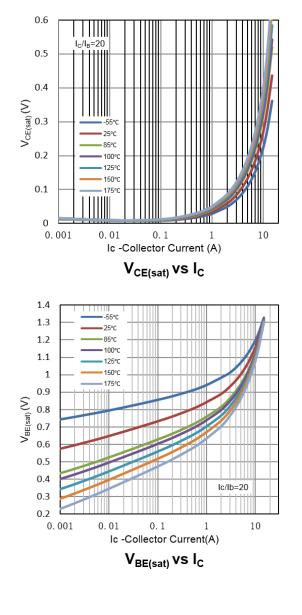
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	100	198	—	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BVCEO	60	79	—	V	Ic = 10mA
Emitter-Base Breakdown Voltage	BVEBO	7	8.4	—	V	I <sub>E</sub> = 100μA
Collector Cut-off Current		_	2	50	nA	V <sub>CB</sub> = 100V
Collector Cut-on Current	Ісво	_	0.05	10	μA	V <sub>CB</sub> = 100V, T <sub>A</sub> = +125°C
Collector Cut-off Current	ICER	—	5	100	nA	V <sub>CB</sub> = 60V
	R <sub>B</sub> ≤1kΩ	—	0.2	10	μA	$V_{CB} = 60V, T_A = +125^{\circ}C$
Emitter Cut-off Current	I <sub>EBO</sub>	—	1	20	nA	$V_{EB} = 6V$
		100	197	—	—	Ic = 10mA, VcE = 2V
		100	195	400	—	IC = 1A, VCE = 2V
DC Current Gain (Note 9)	hFE	100	194	300	—	Ic = 2A, Vce = 2V
		55	117	—	—	Ic = 5A, Vce = 2V
		20	50	—	—	Ic = 10A, Vce = 2V
		_	15	30	mV	Ic = 100mA, I <sub>B</sub> = 5mA
		_	35	60	mV	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_	42	70	mV	$I_{\rm C} = 1$ A, $I_{\rm B} = 50$ mA
		_	86	135	mV	Ic = 2A, I <sub>B</sub> = 50mA
		_	176	260	mV	Ic = 6A, I <sub>B</sub> = 300mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	_	986	1100	mV	Ic = 6A, I <sub>B</sub> = 300mA
Base-Emitter Turn-On Voltage (Note 9)	VBE(on)	_	916	1000	mV	Ic = 6A, Vce = 1V
Input Capacitance	Cibo	_	563	—	pF	V <sub>EB</sub> = 0.5V. f = 1MHz
Output Capacitance	Cobo	_	26	—	pF	Vсв = 10V. f = 1MHz
Current Gain-Bandwidth Product	fт	_	140	—	MHz	$V_{CE} = 5V, I_C = 100mA, f = 100MHz$
	t <sub>delay</sub>	_	17.9	—	ns	
Suitabing Time	t <sub>rise</sub>	_	6.1	—	ns	Ic = 1A, Vcc = 10V,
Switching Time	t <sub>storage</sub>	_	1256	—	ns	I <sub>B1</sub> = -I <sub>B2</sub> = 100mA
	t <sub>fall</sub>	_	27.6	_	ns	

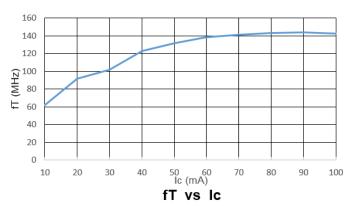
Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



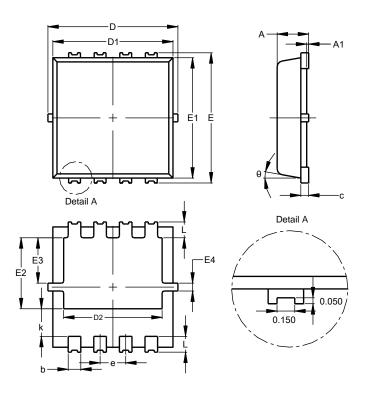






#### **Package Outline Dimensions**

Please see https://www.diodes.com/package-outlines.html for the latest version.



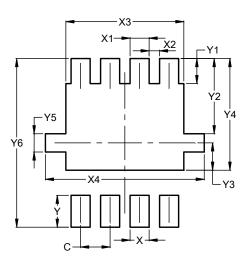
PowerDI3333-8 (SWP)					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
E	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е	_	-	0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All I	All Dimensions in mm				

# **Suggested Pad Layout**

Please see https://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (SWP) (Type UX)

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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